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Absorption spectra due to the $4f^7 \rightarrow 4f^7$ transitions of Gd^{3+} ions in $GdAl_3(BO_3)_4$ crystals

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Abstract. Optical absorption spectra due to the $4f^7 \rightarrow 4f^7$ transitions of Gd^{3+} ions in $GdAl_3(BO_3)_4$ crystals have been measured. The Stark splittings have been observed in the transitions from the ground state ${}^8S_{7/2}$ to the excited states ${}^6P_J(J = 7/2, 5/2, 3/2)$, ${}^6I_J(J = 7/2, 9/2, 17/2, 11/2, 15/2, 13/2)$ and ${}^6D_J(J = 9/2, 1/2, 7/2, 3/2, 5/2)$. It is suggested that the splittings are consistent with the D_{3h} site symmetry of Gd^{3+} . The $4f^7 \rightarrow 4f^7$ spectrum is compared with that of Gd^{3+} in solution.

1. Introduction

The Gd³⁺ ion has the electronic configuration $4f^75s^25p^6$ (named $4f^7$ hereafter) in the outer shell. The $4f^7$ configuration has the ground state ${}^8S_{7/2}$ and the excited state multiplets ${}^6P_J(J = 7/2, 5/2, 3/2 \text{ in order of increasing energy})$, ${}^6I_J(J = 7/2, 9/2, 17/2, 11/2, 15/2, 13/2)$ and ${}^6D_J(J = 9/2, 1/2, 7/2, 3/2, 5/2)$ with increasing energy. These excited states are located at 32 000–41 000 cm⁻¹ above the ground state [1, 2]. The positions and order of the multiplets are almost the same in various materials (even if they are aqueous solutions) since the $4f^7$ electrons are shielded by the outer $5s^25p^6$ electrons from the surrounding ions of Gd³⁺. In addition to these excited states the other $4f^7$ states (e.g. 6F_J and 4H_J) and the $4f^65d$ states are located in the vacuum-ultraviolet region, which have been studied in LiYF₄ [3] and CaF₂ [4], respectively.

The $4f^7({}^8S_{7/2}) \rightarrow 4f^7$ ultraviolet absorption spectra of Gd^{3+} ions have been studied in various materials including not only ionic crystals like SrF_2 with Gd^{3+} impurity [5] but also Gd compounds like $Cs_2NaGdCl_6$ [6], where the observation of absorption lines related to the 6P_J , 6I_J and 6D_J excited states has been observed together with their Stark components. However, to our knowledge, all Stark components of the 6P_J , 6I_J and 6D_J states have not been observed in any Gd^{3+} materials except Gd^{3+} :LaBr₃ [7]: e.g. the Stark components of the ${}^6D_{3/2}$ and ${}^6D_{5/2}$ states in LaCl₃ are missing [8], and the Stark components of the ${}^6I_{15/2}$ and ${}^6I_{13/2}$ states in GdCl₃ · 6H₂O are missing [9], and additionally the ${}^6P_{3/2}$ lines are missing in many materials (see e.g. [7, 10, 11]).

Although the $4f^7 \rightarrow 4f^7$ absorption spectra have been studied in many Gd³⁺ compounds, the absorption spectra of Gd³⁺ in the GdAl₃(BO₃)₄ (called GAB hereafter) crystal have not been studied yet. Wang *et al* have reported the presence of weak absorption due to ${}^{8}S_{7/2} \rightarrow {}^{6}P$ transitions at 300–310 nm in Cr³⁺:GAB, but the detailed study has not been made yet [12]. GAB is used as the bulk crystal of the Ti³⁺:GdAl₃(BO₃)₄ laser [13], and

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additionally crystals with the same crystal structure are used for lasers, e.g. NdAl₃(BO₃)₄ laser [14] and Cr³⁺:YAl₃(BO₃)₄ laser [15]. Therefore not only doped but also undoped GAB might be laser active. In this sense, it is important to study the optical fundamental properties of GAB. Here, taking into account that the whole Gd³⁺ spectra containing all Stark components of the ⁶P_J, ⁶I_J and ⁶D_J states have not been shown for any material, we show the 4f⁷ \rightarrow 4f⁷ absorption spectrum covering from the lowest-energy ⁶P_{7/2} state up to the highest-energy ⁶D_{5/2} state in the GAB crystal.

2. Experimental procedures and results

Single crystals of GAB used in the present study were grown by Dr Guofu Wang at the University of Strathclyde, Glasgow, UK. Absorption spectra were measured using a Cary-5E spectrophotometer at various temperatures in the range 15–300 K. The slit width was set to be 0.03 nm.

The GAB crystal is transparent in the infrared-visible region, while many sharp absorption lines appear in a limited ultraviolet region, i.e. in a 31 900–41 000 cm⁻¹ range (corresponding to about 313–243 nm range in wavelength). The line spectrum does not change on decreasing temperature to 15 K: no change is observed in the line widths and peak heights for all the lines. The line width is almost the same (about 7 cm⁻¹) for all the Stark-split lines. Figures 1 and 2 show the enlarged spectra in the 31 800–33 400 cm⁻¹ and 35 600–41 000 cm⁻¹ ranges, respectively. From comparison with the previous studies of Gd compounds and Gd³⁺ impurities in ionic crystals, these absorption lines are attributed to the $4f^7 \rightarrow 4f^7$ intraconfigurational transitions of Gd³⁺, e.g. the lowest-energy line is attributed to the $^{8}S_{7/2} \rightarrow ^{6}P_{7/2}$ transition. The excited states responsible for the observed lines are shown in figures 1 and 2.

Four, three and two absorption lines are observed in the ${}^8S_{7/2} \rightarrow {}^6P_{7/2}$, ${}^8S_{7/2} \rightarrow {}^6P_{5/2}$ and ${}^8S_{7/2} \rightarrow {}^6P_{3/2}$ transitions, respectively as seen in figure 1. Of the three transitions, the last one is the weakest. At high energies, four, five, one, four, two and three lines are observed



Figure 1. Absorption bands due to the ${}^{8}S_{7/2} \rightarrow {}^{6}P_{7/2}$, ${}^{6}P_{5/2}$ and ${}^{6}P_{3/2}$ transitions of Gd³⁺ ions in the GdAl₃(BO₃)₄ crystal at 296 K. ABS. COEFF., absorption coefficient.



Figure 2. Absorption bands due to the ${}^{8}S_{7/2} \rightarrow {}^{6}I_{J}$ and ${}^{6}D_{J}$ transitions of Gd³⁺ ions in the GdAl₃(BO₃)₄ crystal at 296 K. ABS. COEFF., absorption coefficient.

States	Energy (cm ⁻¹)	States	Energy (cm ⁻¹)	States	Energy (cm ⁻¹)
⁶ P _{7/2}	31974	${}^{6}I_{11/2} + {}^{6}I_{15/2} + {}^{6}I_{13/2}$	36 301	⁶ D _{1/2}	40 358
,	32 073	, , ,	36 338	${}^{6}D_{7/2}$	40 446
	32 055		36 348	,	40 462
	32 070		36 374		40 477
⁶ P _{5/2}	32 591		36 385		40 4 8 3
,	32 641		36 4 1 3	${}^{6}D_{3/2}$	40 623
	32 653		36 444	,	40 666
⁶ P _{3/2}	33 191		36 4 5 3		
,	33 219		36 463	${}^{6}D_{5/2}$	40723
⁶ I _{7/2}	35 686		36 474	,	40 803
,	35736		36 489		40818
	35 7 59		36 502		
	35 792		36 505		
${}^{6}I_{9/2} + {}^{6}I_{17/2}$	36 0 3 1		36510		
	36 0 64		36 550		
	36 094	⁶ D _{9/2}	39 353		
	36113		39 396		
	36117		39 420		
	36129		39 493		
	36134		39 527		
	36143				
	36162				

Table 1. Absorption line positions due to Gd^{3+} in the $GdAl_3(BO_3)_4$ crystal.

in the ${}^8S_{7/2} \rightarrow {}^6I_{7/2}$, ${}^6D_{9/2}$, ${}^6D_{1/2}$, ${}^6D_{7/2}$, ${}^6D_{3/2}$ and ${}^6D_{5/2}$ transitions, respectively, as summarized in table 1. On the other hand, nine lines are observed in the ${}^8S_{7/2} \rightarrow {}^6I_{9/2} + {}^6I_{17/2}$ transitions, while 15 lines in the ${}^8S_{7/2} \rightarrow {}^6I_{11/2} + {}^6I_{15/2} + {}^6I_{13/2}$ transitions, where it is difficult to identify which line belongs to which excited state. In table 2 we give the absorption intensities (i.e. the integrated absorption areas of the whole Stark components) relative to the ${}^8S_{7/2} \rightarrow {}^6P_{7/2}$ absorption intensity. It is observed the intensity of the ${}^8S_{7/2} \rightarrow {}^6P_{3/2}$ absorption is the smallest, and the next is that of the ${}^8S_{7/2} \rightarrow {}^6D_{1/2}$ absorption.

Table	2.	Relative	intensity	of	Gd^{3+}	absorpt	ior
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$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Excited states	$GdAl_3(BO_3)_4$	SrF ₂ [5]	Solution [18]
	⁶ P _{7/2}	1.0	1.0	1.0
	⁶ P _{5/2}	0.651	0.55	0.56
	⁶ P _{3/2}	0.017		0.019
${}^{6}I_{9/2} + {}^{6}I_{17/2}$ 4.175 4.20 11.57 ${}^{6}I_{11/2} + {}^{6}I_{15/2} + {}^{6}I_{13/2}$ 10.255 8.85 26.22 ${}^{6}D_{9/2}$ 1.146 0.16 1.07	⁶ I _{7/2}	0.781	0.44	1.65
${}^{6}I_{11/2} + {}^{6}I_{15/2} + {}^{6}I_{13/2} $ 10.255 8.85 26.22	${}^{6}I_{9/2} + {}^{6}I_{17/2}$	4.175	4.20	11.57
$^{6}D_{0/2}$ 1146 016 107	${}^{6}I_{11/2} + {}^{6}I_{15/2} + {}^{6}I_{13/2}$	10.255	8.85	26.22
1.140 0.10 1.07	⁶ D _{9/2}	1.146	0.16	1.07
⁶ D _{1/2} 0.066 —	${}^{6}D_{1/2}$	0.066	_	
⁶ D _{7/2} 0.774 0.24 1.12	⁶ D _{7/2}	0.774	0.24	1.12
⁶ D _{3/2} 0.365 —	⁶ D _{3/2}	0.365	_	
⁶ D _{5/2} 0.788 —	⁶ D _{5/2}	0.788	_	

3. Discussion

Although the positions of the $4f^7 \rightarrow 4f^7$ absorption lines are little dependent on material, the absorption line shape and the Stark splitting are different from material to material. A relatively small splitting is caused by the crystal field. The ${}^8S_{7/2}$ ground state has a very small Stark splitting of the order of 0.1 cm⁻¹, so that the absorption spectra reflect directly the excited states [9, 11, 16], providing information on the surroundings of Gd³⁺.

The GAB crystal has the trigonal crystal structure which is isomorphous with the mineral huntite $CaMg_3(BO_3)_4$ belonging to the space group R32 as the cases of other borate crystals such as YAl₃(BO₃)₄ and NdAl₃(BO₃)₄. The Gd³⁺ ion occupies a crystallographic site without a centre of inversion and its immediate surroundings consist of a trigonal prism of oxygen anions (symmetry D_{3h}) [17]. The D_{3h} symmetry crystal field removes all but Kramers degeneracy in the electronic states, and the ⁶P_{7/2} state is split into four Kramers degenerate crystal field states [11]. Therefore we expect four absorption lines in the ${}^{8}S_{7/2} \rightarrow {}^{6}P_{7/2}$ transition in GAB as the cases of GdCl₃ · 6H₂O [11] and Gd³⁺:LaCl₃ [7] with the same D_{3h} site symmetry as GAB. Similarly the electronic term with J (J: quantum number of total angular momentum) is expected to show (2J + 1)/2 absorption lines since the number of Stark components in the excited state is (2J + 1)/2 in the D_{3h} crystal field: e.g. the transition to the ${}^{6}D_{9/2}$ (i.e. J = 9/2) state gives rise to five lines. This agrees with the observation except the absorption spectra in the ranges of 36000-36150 and 36 300–36 600 cm⁻¹ (see figures 1 and 2). On the other hand, in the case of Gd^{3+} in LaCl₃, the identification of the observed lines has been made for all the ranges [7]. The reason why the identification is difficult in the two ranges in GAB is that the ${}^{6}I_{9/2}$ and ${}^{6}I_{17/2}$ energy states appearing at the former range are located close to each other and the same is true for the ${}^{6}I_{11/2}$, ${}^{6}I_{15/2}$ and ${}^{6}I_{13/2}$ states appearing in the latter range.

In table 2 we summarize the integrated absorption areas of various excited states in GAB, relative to the ${}^{8}S_{7/2} \rightarrow {}^{6}P_{7/2}$ absorption area (i.e. the absorption area related to the ${}^{6}P_{7/2}$ state is given as 1.0). The absorption related to the ${}^{6}P_{5/2}$ state consists of three lines. The integrated absorption area of this state means the sum of these integrated areas. In this table we also show the cases of Gd³⁺ in the SrF₂ crystal [5] and in dilute acid solution [18]. There is not much difference in the intensity ratios between GAB and SrF₂ crystals. However, there is an obvious difference between crystals and solution: the ${}^{8}S_{7/2} \rightarrow {}^{6}I_{J}$ absorption intensity is considerably larger in solution than in crystals. According to the analysis by Downer *et al* [19], the ${}^{8}S_{7/2} \rightarrow {}^{6}I_{J}$ absorption is caused by the electric dipole

(ED) transition, while the ${}^8S_{7/2} \rightarrow {}^6P_J$ absorption is predominantly caused by the magnetic dipole (MD) transition. Therefore it is suggested that the relatively large ${}^8S_{7/2} \rightarrow {}^6P_J$ absorption intensity observed in crystals (compared with the case of solution) is due to involvement of the ED transition in this parity-forbidden ${}^8S_{7/2} \rightarrow {}^6P_J$ transition, because the ED transition is caused by the mixing of the 4f⁶5d state to the 4f⁷ state by the odd-parity crystal field and because the MD contribution to the absorption intensity is almost independent of the surroundings of the rare-earth ion.

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References

- [1] Crosswhite H M and Moos H W 1967 Optical Properties of Ions in Crystals (New York: Interscience) p vii
- [2] Carnall W T, Fields P R and Rajnak K 1968 J. Chem. Phys. 49 4443-6
- [3] Wegh R T, Douker H, Meijerink A, Lamminmaki R J and Holsa J 1997 Phys. Rev. B 56 13 841
- [4] Szczurek T and Schlesinger M 1984 Rare Earths Spectroscopy ed B Jezowska-Trzebiatowska, J Legendziewicz and W Strek (Singapore: World Scientific) pp 309–30
- [5] Detrio J A 1971 Phys. Rev. B 4 1422-7
- [6] Bouazaoui M, Jacquier B, Linares C and Strek W 1991 J. Phys.: Condens. Matter 3 921-6
- [7] Schwiesow R L and Crosswhite H M 1969 J. Opt. Soc. Am. 59 592-602
- [8] Piksis A H, Dieke G H and Crosswhite H M 1967 J. Chem. Phys. 47 5083–9
- [9] Dieke G H 1968 Spectra and Energy Levels of Rare Earth Ions in Crystals (New York: Interscience) pp 250-2
- [10] Detrio J S, Ferralli M W and Yaney P P 1970 J. Chem. Phys. 53 4372-7
- [11] Couture L 1979 J. Lumin. 18/19 891-6
- [12] Wang G, Han T P J, Gallagher H G and Henderson B 1995 Appl. Phys. Lett. 67 3906-8
- [13] Bantien F, Albers P and Huber G 1987 J. Lumin. 36 363
- [14] Chinn S R and Hong H Y-P 1975 Opt. Commun. 15 345-50
- [15] Iwai M, Mori Y, Sasaki T, Nakai S, Sarukura N, Liu Z and Segawa Y 1995 Japan. J. Appl. Phys. 34 2338-43
- [16] Weber M J 1986 Laser Spectroscopy of Solids ed W M Yen and P M Selzer (Berlin: Springer) ch 6, pp 189–240
- [17] Blasse G, Bril A and Nieupoort W C 1966 J. Phys. Chem. Solids 27 1587-92
- [18] Carnall W T, Fields P R and Rajnak K 1968 J. Chem. Phys. 49 4412-23
- [19] Downer M C, Burdick G W and Sardar D K 1988 J. Chem. Phys. 89 1787-97